

SANKEN ELECTRIC CO LTD

2SC1985
2SC1986

Absolute Maximum Ratings

Symbol	2SC1985	2SC1986	Unit
V_{CB0}	80	100	V
V_{CEO}	60	80	V
V_{EBO}	6		V
I_C	6		A
I_B	3		A
P_C	40 ($T_{FL}=25^\circ\text{C}$)		W
T_J	150		$^\circ\text{C}$
T_{stg}	-55~+150		$^\circ\text{C}$

Silicon NPN Triple Diffused Mesa

☆ Complement to types 2SA770 and 2SA771

Application Example :

General and Industrial Purpose

● Outline Drawing 1.....MT-25(TO220)

● Test Circuit.....③

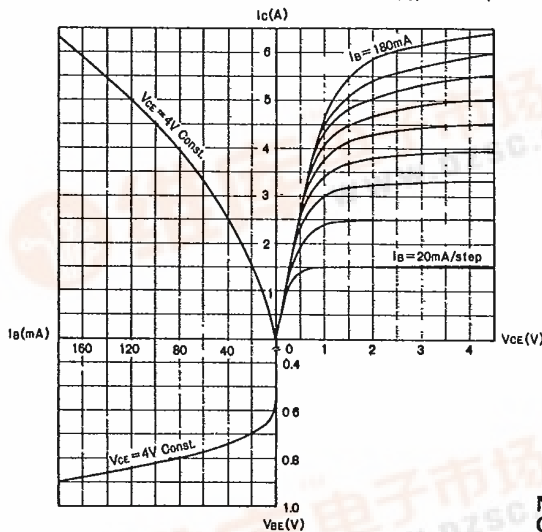
Electrical Characteristics

Symbol	Conditions	2SC1985	2SC1986	Unit
I_{CBO}	$V_{CB}=$	1.0max	1.0max	mA
I_{EBO}	$V_{EB}=6\text{V}$		1.0max	mA
$V_{(BR)CEO}$	$I_C=25\text{mA}$	60min	80min	V
h_{FE}	$V_{CE}=4\text{V}, I_C=1\text{A}$	40min		
$V_{CE(sat)}$	$I_C=3\text{A}, I_B=0.3\text{A}$	1.0max		V
f_T	$V_{CE}=12\text{V}, I_E=-0.5\text{A}$	10typ		MHz

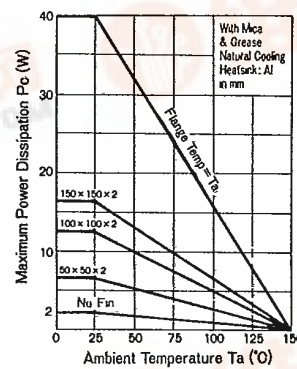
Typical Switching Characteristics (Emitter Common)

V_{CC} (V)	R_L (Ω)	I_C (A)	V_{B2} (V)	I_{B1} (mA)	I_{B2} (mA)	t_r (μs)	t_{stg} (μs)	t_f (μs)
9	3	3	-5	300	-300	1.1typ	1.8typ	0.55typ

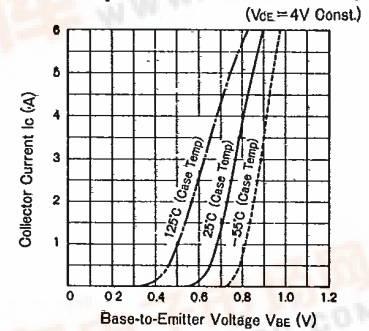
Common Emitter Characteristics (Typical Value)



Power Derating

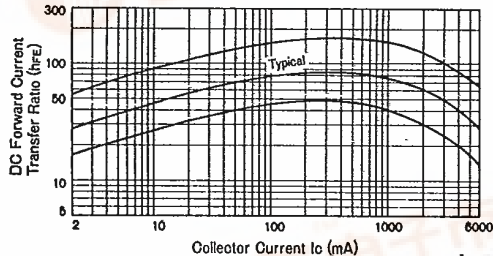


Temperature Characteristics

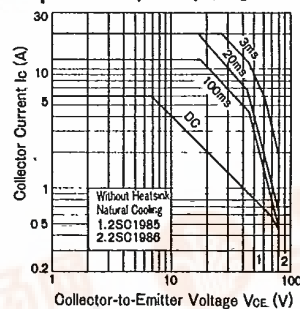


DC Current Gain Characteristics

($V_{CE}=4\text{V Const.}$)

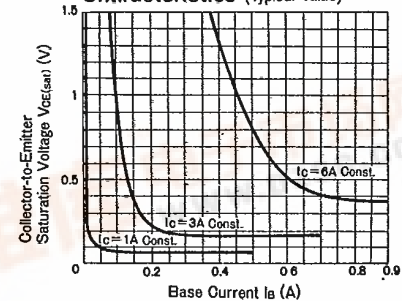


Maximum Areas For Safe Operation (ASO) (Single Pulse)



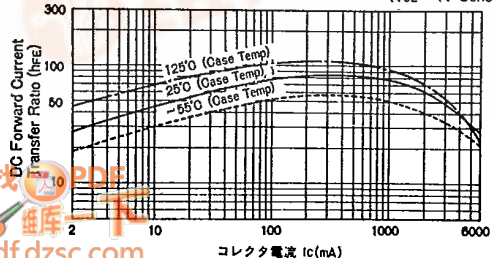
Collector-to-Emitter Saturation Characteristics

(Typical Value)



DC Current Gain Temperature Characteristics

($V_{CE}=4\text{V Const.}$)



Transient Thermal Resistance Characteristics

